



MJE15032G Information



For Reference Only

Part Number MJE15032G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 250V 8A TO220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MJE15032G Specifications

Manufacturer Part Number	MJE15032G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-220-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	8A
Voltage - Collector Emitter Breakdown (Max)	250V
Vce Saturation (Max) @ Ib, Ic	500mV @ 100mA, 1A
Current - Collector Cutoff (Max)	10μA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	10 @ 2A, 5V
Power - Max	2W
Frequency - Transition	30MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3
Supplier Device Package	TO-220AB
	Report errors?

MJE15032G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MJE15032G Payment Methods





















MJE15032G Shipping Methods













If you have any question about MJE15032G, please do not hesitate to contact us!

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